

## **Product Change Notification - JAON-27SGKS288**

Date:

03 Jan 2019

**Product Category:** 

8-bit Microcontrollers

Affected CPNs:



#### **Notification subject:**

CCB 3656, 3656.001 and 3656.002 Initial Notice: Qualification of GTK as a new assembly site for selected Atmel products of 35.5K wafer technology available in 24L SOIC package using palladium coated copper with gold flash (CuPdAu) bond wire.

#### **Notification text:**

**PCN Status:** 

Initial notification

**PCN Type:** 

Manufacturing Change

#### **Microchip Parts Affected:**

Please open one of the icons found in the Affected CPNs section above.

**NOTE:** For your convenience Microchip includes identical files in two formats (.pdf and .xls)

## **Description of Change:**

Qualification of GTK as a new assembly site for selected Atmel products of 35.5K wafer technology available in 24L SOIC package using palladium coated copper with gold flash (CuPdAu) bond wire.

#### **Pre-Change:**

Assembled at ANAP using palladium coated copper (PdCu) or palladium coated gold (AuPd) bond wire, 8290 die attach and G700LS or G600 mold compound material.

## **Post Change:**

Assembled at GTK using palladium coated copper with gold flash (CuPdAu) bond wire, EN-4900GC die attach and G600F mold compound material.

**Pre and Post Change Summary:** 

	Pre-C	hange	Post Change			
Assembly Site	Amkor Techno (P1/P2), Ir		Greatek Electronic Inc. (GTK)			
Wire material	PdCu	AuPd	CuPdAu			
Die attach material	82	90	EN-4900GC			
Molding compound material	G700LS	G600	G600F			
Lead frame material	A1	94	A194			

#### **Impacts to Data Sheet:**

None

**Change Impact:** 

None

#### **Reason for Change:**

To improve on-time delivery performance by qualifying GTK as a new assembly site.

## **Change Implementation Status:**

In Progress

#### **Estimated Qualification Completion Date:**

April 2019

Note: Please be advised the qualification completion times may be extended because of unforeseen



business conditions however implementation will not occur until after qualification has completed and a final PCN has been issued. The final PCN will include the qualification report and estimated first ship date. Also note that after the estimated first ship date guided in the final PCN customers may receive pre and post change parts.

#### **Time Table Summary:**

		Jan	uary 2	2019		>	April 2019					
Workweek	01	02	03	04	05	/	14	15	16	17	18	
Initial PCN Issue Date	X											
Qual Report Availability									X			
Final PCN Issue Date									X			

## Method to Identify Change:

Traceability code.

#### **Qualification Plan:**

Please open the attachments included with this PCN labeled as PCN # Qual Plan.

## **Revision History:**

January 3, 2019: Issued initial notification.

The change described in this PCN does not alter Microchip's current regulatory compliance regarding the material content of the applicable products.

## Attachment(s):

PCN JAON-27SGKS288 Qual Plan.pdf

Please contact your local <u>Microchip sales office</u> with questions or concerns regarding this notification.

#### **Terms and Conditions:**

If you wish to <u>receive Microchip PCNs via email</u> please register for our PCN email service at our <u>PCN home page</u> select register then fill in the required fields. You will find instructions about registering for Microchips PCN email service in the <u>PCN FAQ</u> section.

If you wish to <u>change your PCN profile</u>, <u>including opt out</u>, please go to the <u>PCN home page</u> select login and sign into your myMicrochip account. Select a profile option from the left navigation bar and make the applicable selections.

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Affected Catalog Part Numbers (CPN)

AT90PWM1-16SU

AT90PWM216-16SU

AT90PWM216-16SUR

AT90PWM2-16SQ

AT90PWM2-16SQR

AT90PWM2B-16SU

AT90PWM2B-16SUR

Date: Wednesday, January 02, 2019



# **QUALIFICATION PLAN**

**PCN #: JAON-27SGKS288** 

Date December 12, 2018

Qualification of GTK as a new assembly site for selected Atmel products of 35.5K wafer technology available in 24L SOIC package using palladium coated copper with gold flash (CuPdAu) bond wire.

Title:

Qualification of GTK as a new assembly site for selected Atmel products of 35.5K wafer technology available in 24L SOIC package using palladium coated copper with gold flash (CuPdAu) bond wire. 3656, 3656.001 and 3656.002

CCB No.

	Assembly site	GTK			
Misc.	BD Number	BDM-002032A (GTK1811552CB)			
	MP Code (MPC)	355TA7K3XC02			
	Part Number (CPN)	AT90PWM216-16SU			
	Paddle size	190x220 mil			
	Material	A194			
	DAP Surface Prep (Spot/Ring/Double ring)	Double Ring			
Lead-Frame	Treatment (roughened/ brown oxide(BOT) /micro-etched/ none)	Non roughened			
7-132	Process (stamped/Etched)	Stamped			
ead	Lead-lock (Y/N)	Yes			
	Part Number	11-0224W-007			
	Lead Plating	Matte Sn			
	Strip Size	213.36 x 58.42 mm			
	Strip Density	4 x 10			
Bon d Wire	Material	CuPdAu			
ach ach	Part Number	EN-4900GC			
<u>Die</u> Attach	Conductive	Yes			
MC	Part Number	G600F			
4DI	PKG Type	SOIC			
PKG	Pin/Ball Count	24			
Щ	PKG width/size	300 mils			
-	Die Thickness	15 mils			
Die	Die Size	115x169 mils			
	Fab Process (site)	35.5K (MCSO6)			
	Ship in strip / Singulated	Singulated			
mbly ping	Tray / Tube / Canister	Tube			
Assembly Shipping	Tube Length	20 inches			
	Units per tube	31			
	MSL	MSL 3 / 260			

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Test Name	Conditions	Sample Size	Min. Qty of Spares per Lot (should be properly marked)	Qty of Lots	Total Units	Fail Accept Qty	Est. Dur. Days	Test Site	Special Instructions
Standard Pb-free Solderability	J-STD-002D; Perform 8 hour steam aging for Matte tin finish and 1 hour steam aging for NiPdAu finish prior to testing.  Standard Pb-free: Matte tin/NiPdAu finish, SAC solder, wetting temp 245°C for both SMD & through hole packages.	22	5	1	27	> 95% lead coverage	5	MPHIL	Standard Pb-free solderability is the requirement.  SnPb solderability (backward solderability- SMD reflow soldering) is required for any plating related changes and highly recommended for other package BOM changes.
Wire Bond Pull - WBP	Mil. Std. 883-2011	5	0	1	5	0 fails after TC	5	GTK	30 bonds from a minimum of 5 devices.
Wire Bond Shear - WBS	CDF-AEC-Q100-001	5	0	1	5	0	5	GTK	30 bonds from a minimum of 5 devices.
Physical Dimensions	Measure per JESD22 B100 and B108	10	0	3	30	0	5	MPHIL	
External Visual	Mil. Std. 883-2009/2010	All devices prior to submission for qualification testing	0	3	ALL	0	5	MPHIL	
HTSL (High Temp Storage Life)	+175 C for 504 hours or 150°C for 1008 hrs. Electrical test pre and post stress at +25C and hot temp.	45	5	1	50	0	10	MPHIL	Must be in progress at time of package release to production, but completion is not required for release to production.
Preconditioning - Required for surface mount devices	+150°C Bake for 24 hours, moisture loading requirements per MSL level + 3X reflow at peak reflow temperature per Jedec-STD-020E for package type; Electrical test pre and post stress at +25°C.  MSL3 – 260'C	231	15	3	738	0	15	MPHIL	Spares should be properly identified. 77 parts from each lot to be used for HAST, Autoclave, Temp Cycle test.
HAST	+130°C/85% RH for 96 hours Electrical test pre and post stress at +25°C and hot temp.	77	5	3	246	0	10	MPHIL	Spares should be properly identified. Use the parts which have gone through Pre-conditioning.

Test Name	Conditions	Sample Size	Min. Qty of Spares per Lot (should be properly marked)		Total Units	Fail Accept Qty	Est. Dur. Days	Test Site	Special Instructions
Unbiased HAST	'+130°C/85% RH for 96 hrs Electrical test pre and post stress at +25°C	77	5	3	246	0	10	MPHIL	Spares should be properly identified. Use the parts which have gone through Pre-conditioning.
Temp Cycle	-65°C to +150°C for 500 cycles and 100cycles. Electrical test pre and post stress at hot temp; 3-gram force WBP, on 5 devices from 1 lot, test following Temp Cycle stress.	77	5	3	246	0	15	MPHIL	Spares should be properly identified. Use the parts which have gone through Pre-conditioning.